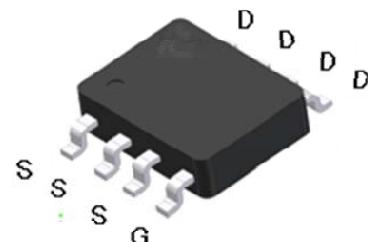
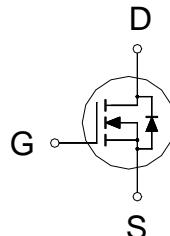


N-Channel Logic Level Enhancement Mode Field Effect Transistor

Product Summary:

| | |
|--------------------------|-----|
| BV _{DSS} | 30V |
| R _{DSON} (MAX.) | 6mΩ |
| I _D | 18A |



UIS, R_G 100% Tested

Pb-Free Lead Plating



ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C Unless Otherwise Noted)

| PARAMETERS/TEST CONDITIONS | | SYMBOL | LIMITS | UNIT |
|--|---------------------------|-----------------------------------|------------|------|
| Gate-Source Voltage | | V _{GS} | ±20 | V |
| Continuous Drain Current | T _A = 25 °C | I _D | 18 | A |
| | T _A = 100 °C | | 12 | |
| Pulsed Drain Current ¹ | | I _{DM} | 72 | |
| Avalanche Current | | I _{AS} | 20 | |
| Avalanche Energy | L = 0.1mH, ID=20A, RG=25Ω | E _{AS} | 20 | mJ |
| Repetitive Avalanche Energy ² | L = 0.05mH | E _{AR} | 10 | |
| Power Dissipation | T _A = 25 °C | P _D | 2.5 | W |
| | T _A = 100 °C | | 1 | |
| Operating Junction & Storage Temperature Range | | T _j , T _{stg} | -55 to 150 | °C |

THERMAL RESISTANCE RATINGS

| THERMAL RESISTANCE | SYMBOL | TYPICAL | MAXIMUM | UNIT |
|----------------------------------|------------------|---------|---------|--------|
| Junction-to-Case | R _{θJC} | 25 | 50 | °C / W |
| Junction-to-Ambient ³ | R _{θJA} | | | |

¹Pulse width limited by maximum junction temperature.

²Duty cycle ≤ 1%

³50°C / W when mounted on a 1 in² pad of 2 oz copper.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, Unless Otherwise Noted)

| PARAMETER | SYMBOL | TEST CONDITIONS | LIMITS | | | UNIT |
|---|-----------------------------|---|--------|------|-----------|------------------|
| | | | MIN | TYP | MAX | |
| STATIC | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(\text{BR})\text{DSS}}$ | $V_{GS} = 0V, I_D = 250\mu\text{A}$ | 30 | | | V |
| Gate Threshold Voltage | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | 1 | 1.5 | 3 | |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0V, V_{GS} = \pm 20V$ | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 24V, V_{GS} = 0V$ | | | 1 | μA |
| | | $V_{DS} = 20V, V_{GS} = 0V, T_J = 125^\circ\text{C}$ | | | 25 | |
| On-State Drain Current ¹ | $I_{D(\text{ON})}$ | $V_{DS} = 10V, V_{GS} = 10V$ | 18 | | | A |
| Drain-Source On-State Resistance ¹ | $R_{DS(\text{ON})}$ | $V_{GS} = 10V, I_D = 18\text{A}$ | | 5.3 | 6 | $\text{m}\Omega$ |
| | | $V_{GS} = 4.5V, I_D = 12\text{A}$ | | 7.5 | 9.5 | |
| Forward Transconductance ¹ | g_{fs} | $V_{DS} = 5V, I_D = 18\text{A}$ | | 25 | | S |
| DYNAMIC | | | | | | |
| Input Capacitance | C_{iss} | $V_{GS} = 0V, V_{DS} = 15V, f = 1\text{MHz}$ | | 1983 | | pF |
| Output Capacitance | C_{oss} | | | 328 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 287 | | |
| Gate Resistance | R_g | $V_{GS} = 15\text{mV}, V_{DS} = 0V, f = 1\text{MHz}$ | | 1.2 | | Ω |
| Total Gate Charge ^{1,2} | $Q_g(V_{GS}=10V)$ | $V_{DS} = 15V, V_{GS} = 10V, I_D = 18\text{A}$ | | 34.6 | | nC |
| | $Q_g(V_{GS}=4.5V)$ | | | 21 | | |
| Gate-Source Charge ^{1,2} | Q_{gs} | | | 4.8 | | |
| Gate-Drain Charge ^{1,2} | Q_{gd} | | | 9.7 | | |
| Turn-On Delay Time ^{1,2} | $t_{d(on)}$ | $V_{DS} = 15V, I_D = 1\text{A}, V_{GS} = 10V, R_{GS} = 2.7\Omega$ | | 9 | | nS |
| Rise Time ^{1,2} | t_r | | | 20 | | |
| Turn-Off Delay Time ^{1,2} | $t_{d(off)}$ | | | 25 | | |
| Fall Time ^{1,2} | t_f | | | 3 | | |
| SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_c = 25^\circ\text{C}$) | | | | | | |
| Continuous Current | I_S | $I_F = I_S, V_{GS} = 0V$ | | | 4 | A |
| Pulsed Current ³ | I_{SM} | | | | 40 | |
| Forward Voltage ¹ | V_{SD} | | | | 1.2 | |
| Reverse Recovery Time | t_{rr} | | | 32 | | |
| Peak Reverse Recovery Current | $I_{RM(\text{REC})}$ | | | 40 | | |
| Reverse Recovery Charge | Q_{rr} | | | 12 | | |

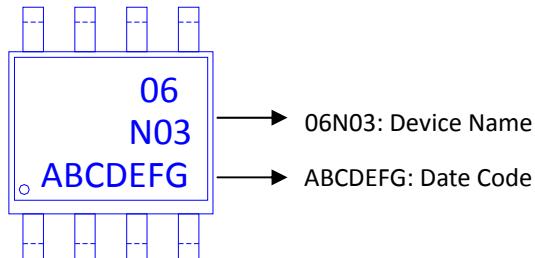
¹Pulse test : Pulse Width $\leq 300\mu$ sec, Duty Cycle $\leq 2\%$.

²Independent of operating temperature.

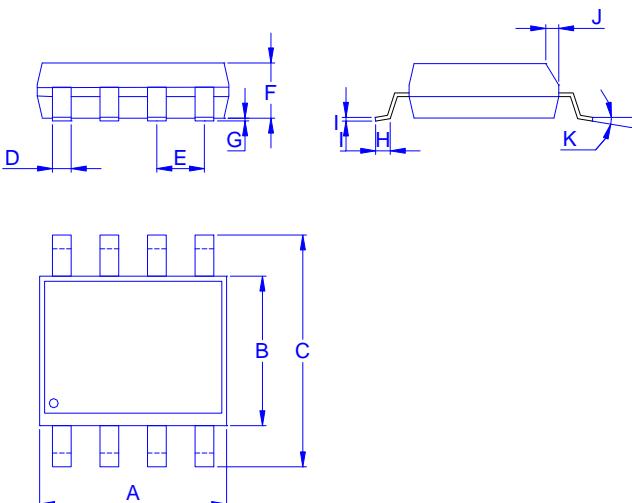
³Pulse width limited by maximum junction

Ordering & Marking Information:
temperature.

Device Name: LB06N03H for SOP-8



Outline Drawing



Dimension in mm

| Dimension | A | B | C | D | E | F | G | H | I | J | K |
|-----------|------|------|------|------|------|------|------|------|------|------|----|
| in. | 4.70 | 3.70 | 5.80 | 0.33 | | 1.20 | 0.08 | 0.40 | 0.19 | 0.25 | 0° |
| Typ. | | | | | 1.27 | | | | | | |
| Max. | 5.10 | 4.10 | 6.20 | 0.51 | | 1.62 | 0.28 | 0.83 | 0.26 | 0.50 | 8° |

